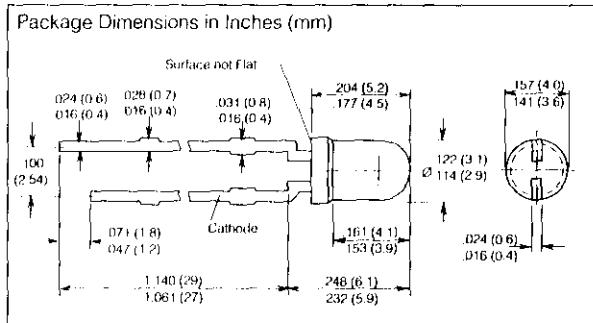
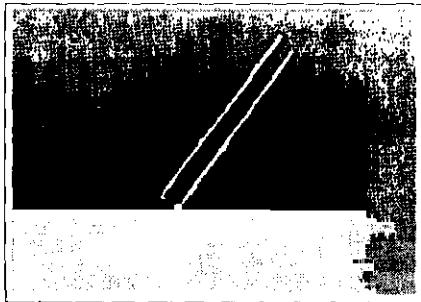


SIEMENS
DOUBLE HETERO JUNCTION LH 3344-QO
DOUBLE HETERO JUNCTION LH 3364-MO
Hyper-Red GaAlAs T1 (3mm) LED Lamp

 LED Lamps
4

FEATURES

- T1 (3mm) Package
- Double Hetero Junction Technology
- Choice of Diffused Lens-LH3364 or Red Clear Lens-LH 3344
- High Luminous Intensity
- Excellent Light Efficiency for Low Current Operation
- IC Compatible

DESCRIPTION

The T1 hyper-red GaAlAs LED lamps use double hetero junction material to produce very high luminous intensities. When operated at very low currents (1 mA) these lamps can produce luminous intensities comparable to standard and high efficiency LEDs that operate at 10 mA to 20 mA.

Luminous Intensity and Lens Type

Part No.	Lens Type	Luminous Intensity*	
		I _f = 10 mA, I _v (mcd)	
LH 3344-QO	red clear	150	63
LH 3364-MO	red diffused	40	16

See graph numbers 1, 2G (LH 3344), 2H (LH 3364), 3A, 4B, 5A, 6A, 7A, 8A, 9A, 10A, 10B (LH 3344, LH 3364) in the back of this section.

Maximum Ratings

Operating Temperature Range (T _{OP})	-55°C to + 100°C
Storage Temperature Range (T _{STG})	-55°C to +100°C
Junction Temperature (T _J)	+ 100°C
Reverse Voltage (V _R)	3 V
Forward Current (I _f)	40 mA
Surge Current (I _s)	0.5 A
Power Dissipation (P _{TOT}) T _A =25°C	120 mW
Thermal Resistance, Junction to Air (R _{THJA})	400 K/W

Characteristics (T_A=25°C) All values typical unless otherwise noted.

Parameter	Symbol	Unit
Peak Wavelength (I _f =20 mA)	λ _{PEAK}	nm
Dominant Wavelength (I _f =20 mA)	λ _{DOM}	nm
Spectral Bandwidth (50% I _{RELMAX} , I _f = 20 mA)	Δλ	nm
Viewing Angle 50% I _v		
LH3344	2 φ	Deg.
LH3364	2 φ	Deg.
Forward Voltage (I _f =10 mA)	V _F	V
Reverse Current (V _R = 3 V)	I _R	(≤2.6) μA
Capacitance (V _R =0 V, f=1 MHz)	C ₀	0.01 pF
Switching Times (I _f =100 mA, t _p =10 μs, R _L =50 Ω)		
Rise time-10% to 90%	t _R	140 ns
Fall time 90% to 10%	t _F	110 ns

* Luminous intensity ratio of one packaging unit I_{VMAX}/I_{VMIN} ≤2